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TERMINAL		DRAWINGS		CLAIMS ALLOWED		
☐ DISCLAIMER	Sheets Drwg.	Figs. Drwg.	Print Fig.	Total Claims	Print Claim for O.G.	
☐ The term of this patent				NOTICE OF ALLOWANCE MAILED		
subsequent to (date) has been disclaimed.	(Assistant	Examiner)	(Date)			
The term of this patent shall not extend beyond the expiration date						
of U.S Patent. No.	İ			ISSUE FEE		
			Ī	Amount Due	Date Paid	
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WARNING: The information disclosed herein may be rest Possession outside the U.S. Patent & Tradem	ricted. Unauthorized of ark Office is restricted	fisclosure may be to authorized empl	prohibited by the U	nited States Code Title 3	5, Sections 122, 181 and 368.	
orn PTO-438A lev. 6/99)			FILED WITH:	DISK (CRF)	FICHE CD-RON	

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